Electrochemical behavior and Li Diffusion study of LiCoO₂ thin film electrodes prepared by PLD

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Abstract — Preferred c-axis oriented LiCoO₂ thin films were prepared on the SiO₂/Si (SOS) substrates by pulsed laser deposition (PLD). Thin film electrodes without carbon and binder are ideal samples to study the electrochemical properties of materials. We did galvanostatic charge/discharge measurements between 3 and 4.7 V on the Li/LiCoO₂ cell to study its electrochemical behavior. Potentiostatic intermittent titration technique (PITT) was used to measure the Li diffusivity in the LiCoO₂ film at different Li concentrations (0.15 < x < 0.75). The dependence of Li diffusivity on the c-lattice parameter and valence of cobalt ions is discussed.

Keywords — LiCoO₂, Thin film; Li diffusion; Pulsed laser deposition

I. INTRODUCTION

For lithium-ion batteries, LiCoO₂ is the most commonly used cathode material due to its high capacity and good cyclability [1-2]. Though its theoretical capacity is 272 mAh/g, the reversible capacity is limited to 140 mAh/g when the LiCoO₂ is cycled between 3 and 4.2 V, corresponding to extracting and inserting about 0.5 Li per LiCoO₂. In order to obtain higher capacity from LiCoO₂, a cutoff voltage above 4.2 V must be applied which sometimes results in a rapid capacity loss. Because of the increasing interest in charging LiCoO₂ to voltage above 4.2 V, it is necessary to investigate the electrochemical behavior above 4.2 V.

Lithium diffusion in the electrodes is a key factor that determines the rate at which a battery can be charged and discharged. With increasing interest in high power density, the kinetics of Li diffusion becomes more important. Many diffusion measurements on LiCoO₂ have been performed on composite electrodes consisting of graphite, binders and other materials. However, a detailed analysis of diffusion coefficients is difficult for composite electrodes because of their non-uniform potential distributions and unknown electrode surface area. Without carbon and binder, thin film electrodes are ideal samples to investigate the intrinsic properties of materials. The dense and flat thin film electrode with known composition and well-defined geometry may be more appropriate for diffusion measurements.

LiCoO₂ thin film electrodes have been successfully prepared by various techniques such as radio frequency (rf) sputtering [3], pulsed laser deposition (PLD) [4], chemical vapor deposition [5], spin coating [6] and electrostatic spray deposition (ESD) [7]. Among them, PLD is a powerful and flexible technique for fabricating simple and complex metal oxide films, and has several advantages for thin film deposition: (1) Direct stoichiometry transfer from the target to the growing film. (2) High deposition rate and inherent simplicity for the growth of multilayered structures. (3) Dense, textured films can be produced more easily by PLD with in situ substrate heating.

In this work, LiCoO₂ thin films were prepared on the SiO₂/Si substrates by PLD. The microstructure and surface morphology of thin films were characterized by X-ray diffraction (XRD) and Field emission scanning electron microscopy (FESEM). The crack-free and well-crystalized LiCoO₂ thin films with smooth surfaces were used to study the electrochemical behavior and Li diffusion of this material.

II. EXPERIMENTAL

A. Thin film deposition

LiCoO₂ thin films were grown on the Si substrates at a substrate temperature of 600°C in an oxygen atmosphere of 100 mTorr for 40 min by PLD with a non-stoichiometric LiCoO₂ target with 15% excess Li₂O to compensate for lithium loss during the deposition. The target-substrate distance was kept at 40 mm. During deposition, the target was rotated at 10-20 rpm to avoid depletion of material at
any given spot. A Lambda Physik KrF excimer laser with wavelength 248 nm was used in the deposition. Laser fluence was controlled at 2 J/cm² and a repetition rate at 10 Hz. In case of the SOS substrate, a double layer of Pt/Ti was deposited on it, where Pt was used as current collector and Ti was used as a buffer layer to enhance the adhesion between the Pt and SiO₂ interface.

**B. Microstructure and surface morphology characterization**

Structure and crystallinity of the thin film samples were measured using a Shimadzu XRD-6000 X-ray diffractometer with Cu Kα radiation. Data were collected in the 2θ range of 10 – 70° at a scan rate of 2°/min. Surface morphology and roughness of thin films were characterized using a Hitachi S-4100 Field emission scanning electron microscopy (FESEM). The cross-section of thin film on the SOS substrate was observed by FESEM to estimate the thin film thickness and the growth rate.

**C. Electrochemical Measurements**

The Li/LiCoO₂ cell was assembled using the LiCoO₂ thin film as the cathode and a lithium metal foil as the anode and a 1 M LiPF₆ in ethyl carbonate/dimethyl carbonate solution (EC/DEC, 1/1 Vol%) Ozark Florence Specialties, Inc.) as the electrolyte. All electrochemical experiments were conducted in an Ar-filled glove box using a Solatron 1287 two-terminal cell test system. Galvanostatic charge/discharge tests were carried out between 3 and 4.7 V using a constant current density of 15 µA/cm². To measure the chemical diffusion coefficient of Li in the LiCoO₂ film by potentiostatic intermittent titration technique (PITT), a potential step of 10 mV was applied and the current was measured as a function of time. The potential step was stepped to the next level when the current dropped below 0.1 µA/cm². This procedure was repeated between 3.88 and 4.50 Vat both increasing and decreasing potentials.

**III. RESULTS AND DISCUSSION**

The layered form of LiCoO₂, which has rhombohedral symmetry and belongs to the space group R3m, is ideally suited to accommodate large changes in Li concentration. This crystal structure of closed-packed oxygen layers stacked in an ABC sequence with Co and Li ions residing in octahedral sites in alternating layers between the oxygen planes. Figure 1 illustrates the crystal structure of the layered form of LiCoO₂. Figure 2 shows the XRD spectra of the bare SOS substrate by itself and of the LiCoO₂ thin film deposited on the substrate. The spectrum of the LiCoO₂ film shows a very strong (003) diffraction peak at 18.90°. Besides the sharp and strong (003) peak, another two small peaks at 38.40° and 59.14° can be attributed to (006) and (009) diffractions of rhombohedral LiCoO₂. The strong and sharp (003) diffraction peak indicates that the film has a high degree of crystallinity. Other diffraction peaks of LiCoO₂ such as (101) and (104) in this scan range can not be detected, indicating that the film has a preferred c-axis (003) out-of-plane orientation. According to the literature [3,8], all LiCoO₂ thin films will develop the preferred (003) texture no matter what deposition method used when the film is less than 0.5 µm thick. The preferred (003) texture of the thin film is due to the lowest surface energy of (003) plane. However, when the film is getting thick (> 0.5 µm), the preferred (003) texture will gradually disappear and be replaced by the preferred (101)-(104) texture as a result of the tendency to minimize the volume strain energy developed in the film during the deposition. The preferred (003) texture of the LiCoO₂ film will block the Li diffusion because no Li layer channel is open at the surface to the electrolyte. In this case, Li ion transport is carried mainly through the grain boundaries of the film.
substances. It can be seen that the film is composed of well-defined grains and has a very smooth surface without any pinholes or cracks. The average grain size is about 200 nm. From the cross-section view of the film on the SOS substrate, we can estimate the thin film thickness is about 300 nm and growth rate of LiCoO$_2$ thin film by PLD is about 7.5 nm/min.

From the XRD and FESEM results, it is clear that the film deposited by PLD has a high degree of crystallinity with layered structure and well-defined geometry. To further understand the electrochemical behavior of this thin film electrode, charge/discharge measurement was performed between 3 and 4.7 V at a current of 15 µA/cm$^2$ (C/2 rate). The typical charge/discharge curves of the LiCoO$_2$ thin film are shown in Figure 4. It can be seen that the charge and discharge curves are highly reversible with only a small amount irreversible capacity. Though the upper cutoff voltage is as high as 4.7 V, the charge and discharge curve only show a small polarization. According to literature [9,10], the upper cutoff voltage of LiCoO$_2$ is often limited to 4.2 V, corresponding to extracting and inserting 0.5 Li per LiCoO$_2$. Using a higher upper cutoff voltage above 4.2 V often results in fast capacity fade. According to literature [11,12], when LiCoO$_2$ is slow charged to 4.7 V, all lithium ions can be removed from LiCoO$_2$. As shown in Figure 4, the charge capacity is about 27 µAh/cm$^2$ when charged to 4.7 V while the charge capacity is about 15 µAh/cm$^2$ when charged to 4.2 V, which indicates that the film is not really fully delithiated when charged to 4.7 V. This is probably due to the rate limitation at high voltage which limits all lithium ions to be extracted at a fast charge rate. Structural phase transitions are often detrimental to the structural stability of the electrode material and will result in structure degradation and fast capacity fade. As shown in Figure 4, it is clear to see 5 voltage plateaus for both charge and discharge curves. The three voltage plateaus below 4.2 volt are well known in previous studies to LiCoO$_2$. The two voltage plateaus above 4.5 V have been found recently from the composite electrode [11] and attributed to two new phase transitions at high voltages.

In order to better understand the phase transitions at different charge states, the voltage profile as a function of Li concentration and the corresponding differential capacity, dQ/dV curves are shown in Figure 5. It is clear to see all phase transitions in all Li concentration range. The phase transition between 0.75 < x < 0.95 corresponds to the first order metal-insulator transition between two hexagonal phases [13]. Another two phase transitions around x = 0.5 correspond to the order/disorder transitions near composition Li$_{0.5}$CoO$_2$ [14]. The observation of another two
phase transitions below \( x < 0.2 \) agrees well with Chen and Dahn’s observation [11] on a LiCoO\(_2\) composite electrode, who attributed these two peaks to the phase transitions from the O3 phase to the H1-3 phase and from the H1-3 phase to the O1 phase, as predicted by Van der Ven and Ceder [15]. The O3 and O1 phase are respectively the rhombohedral and hexagonal form of Li\(_x\)CoO\(_2\), and the H1-3 phase is the stage II compound of Li\(_x\)CoO\(_2\) which can be considered as a hybrid of the rhombohedral and hexagonal host. According to Amatuucci et al.’s paper [16], these two phase transitions accompany severe structure changes, which is probably the reason why fast capacity fade was often observed when LiCoO\(_2\) cycled to 4.7 V.

Besides the structural phase transitions at high voltage, Li diffusion is also very important to the performance of LiCoO\(_2\) at high voltages. The Li diffusion mechanism is believed to be the tetrahedral site hop (TSH) mechanism [17]. It is known that Li is coordinated octahedrally by oxygens. If the lithium ion hops into a vacancy that is part of a divacancy then the minimum energy path passes through the tetrahedral site centered between the two vacancies and the initial site of the hop. The schematic diffusion path of lithium ion is shown in Figure 6. As shown in Figure 6, the Li ion migrates from one octahedral site to another by passing through an intermediate tetrahedral site. The tetrahedral site along the TSH migration path shares a face with an oxygen octahedron around a cobalt ion. The lithium ion in the tetrahedral site therefore experiences a large electrostatic repulsion from the positively charged Co ion. The chemical diffusion coefficient of Li in Li\(_x\)CoO\(_2\) is expected to be influenced by several factors: (i) the concentration of vacancy sites available for lithium ions to hop, (ii) the activation barrier for lithium ions to hop, and (iii) the thermodynamic factor. The concentration of vacancy sites increases with decreasing Li concentration. As discussed by Van der Ven and Ceder [18], the variation of the activation barrier can be attributed to two factors. One is the \( c \)-lattice parameter. A drop of the \( c \)-lattice parameter will reduce the distance between the oxygen planes, and compress the tetrahedral site resulting in an increase in the activation barrier. A second factor is the change in effective valence of the cobalt ions with Li concentration. As Li concentration is reduced, the effective positive charge on Co increases causing the activation barrier to increase. The thermodynamic factor is a measure of the deviation of the chemical potential from that for an ideal solution.

Figure 7 shows the chemical diffusion coefficients of Li vs. \( x \) in Li\(_x\)CoO\(_2\) film during the charge process by PITT. The values of \( \bar{D}_I \) in the Li concentration range 0.15 < \( x \) < 0.75 vary from \( 10^{-12} \) to \( 10^{-11} \) cm\(^2\)s\(^{-1}\), agreeing well the values obtained previously from LiCoO\(_2\) electrodes [19-20]. Figure 8 shows the calculated value for the chemical diffusion coefficient of Li in Li\(_x\)CoO\(_2\) at 400 K by Van der Ven and Ceder [18]. Since a rigorous first-principles calculation of the hop prefactor \( v^* \), they have normalized the diffusion coefficient in Fig. 8 by \( 10^{13}/v^* \), where \( 10^{13} \) sec\(^{-1}\) is typically a good approximation for \( v^* \). It can be seen that our experimental result agree well with the calculated result. In high Li concentration range (0.5 < \( x \) < 0.75), \( \bar{D}_I \) will increase as the \( x \) decreases. In this Li concentration range, the \( c \)-lattice parameter increases only slightly with decreasing Li concentration and the activation barrier does not change much. Therefore, in this composition range, the chemical diffusion coefficient of Li is mainly influenced by
the increasing concentration of Li vacancies. In low Li concentration range \(x < 0.4\), \(D_{Li}\) will decrease as the \(x\) decreases. Figure 9 shows the variation of \(c\)-lattice parameter during lithium extraction of LiCoO\(_2\) by Amatucci et al. It is clear that the \(c\)-lattice parameter starts to decrease when \(x < 0.4\). Therefore when \(x < 0.4\), the \(c\)-lattice parameter decreases, and the charge on Co ion increases with decreasing Li concentration, resulting in a significant increase in the activation barrier energy.

Though there is a good agreement between the experimental result and previously calculated result for Li diffusivity in LiCoO\(_2\), an obvious discrepancy exists. As shown in Figure 7, the experimental result shows a maximum at about \(x = 0.5\). However, the calculated result shows a minimum at \(x = 0.5\) as shown in Figure 8. The chemical diffusion coefficient \(D_{Li}\) is a product of the self-diffusion coefficient \(D_{Li}\) and the thermodynamic factor \(\theta\), which is proportional to \(-dV/dx\), with \(-dV/dx\) will have minima at the phase boundaries near the composition Li\(_{0.5}\)CoO\(_2\) and a maximum at the composition Li\(_{0.5}\)CoO\(_2\) [21,22]. As discussed by Van der Ven and Ceder [18], the self-diffusion coefficient \(D_{Li}\) should have a minimum at \(x = 0.5\) due to the higher activation energy associated with Li hops in ordered Li\(_0.5\)CoO\(_2\). Whether the chemical diffusion coefficient, \(D_{Li}\), is maximal or minimal depends on the balance between the thermodynamic factor and the self-diffusion coefficient. A less-ordered Li\(_0.5\)CoO\(_2\) cathode will exhibit a less deep minimum of \(D_{Li}\) as there would be less limitation to Li hopping. The thermodynamic factor, on the other hand, is an averaged quantity and is likely to be less drastically influenced by the state of order. Hence in real sample, which are less ordered than in simulations, the thermodynamic factor may dominate and lead to a maximum.

Though it is difficult to measure the chemical diffusion coefficient of Li above 4.5 V \((x < 0.15)\) because PITT is only meaningful in a single phase region, it is reasonable to believe that an even faster drop of the Li diffusion will occur when the LiCoO\(_2\) film is further charged to 4.6 and 4.7 V. According to the experimental result by Amatucci et al. [16] (Figure 9), the \(c\)-lattice drops more significantly when LiCoO\(_2\) goes through the two phase transitions from the O3 to the H1-3 phase and from the H1-3 phase to the O1 phase. As discussed previously, a drop of the \(c\)-lattice parameter will increase the activation barrier for Li hopping. In the meanwhile, the effective valence of Co ions will increase as the Li concentration decrease, which will also cause the activation barrier to increase. Figure 10 shows the Co 2p XPS spectra of the as-deposited LiCoO\(_2\) film and the film charged to 4.8 V at the surface region. It is clear to see the transformation from Co\(^{3+}\) to Co\(^{4+}\) during the delithiation. The severe drop of \(c\)-lattice parameter and the increase of the effective valence of Co ions above 4.5 V will result in a fast drop of Li diffusion in the material. The structural phase transitions above 4.5 V together with the decreasing Li diffusivity, which makes Li composition gradients larger, likely leads to large internal strains, and subsequent mechanical degradation of the material. Therefore, the sluggish Li diffusion accompanying the large internal strains above 4.5 V for LiCoO\(_2\) may limit the use of LiCoO\(_2\) electrodes at high voltages above 4.5 V.

IV. CONCLUSIONS

Well-crystallized LiCoO\(_2\) thin film electrodes with smooth surfaces have been prepared by PLD on the SOS substrates. The charge/discharge curves of the Li/LiCoO\(_2\) cell show 5 voltage plateaus between 3 and 4.7 V. Two phase transitions were observed above 4.5 V, which are attributed to the phase transition from the O3 to the H1-3 and the phase transition from the H1-3 to the O1 phase. The chemical diffusion coefficient measured by PITT varies from \(10^{11}\) to \(10^{12}\) cm\(^2\)/s in the Li concentration range \(0.15 < x < 0.75\). The experimental result of Li diffusivity agrees well the calculated result. In high Li concentration range \((x > 0.5)\), Li diffusivity increases as the Li concentration decreases due to the increase of the concentration of Li vacancies. In low Li concentration range \((x < 0.4)\), Li diffusivity decreases as the...
Li concentration decreases due to the drop of the c-lattice parameter and the increase of effective valence of Co ions. The structural phase transitions and the sluggish Li diffusivity above 4.5 V will limit the use of LiCoO$_2$ electrodes at high voltages above 4.5 V.

ACKNOWLEDGMENT

This research was supported by Advanced Materials for Micro- and Nano- System (AMM&NS) program under Singapore-MIT Alliance (SMA) and by National University of Singapore.

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